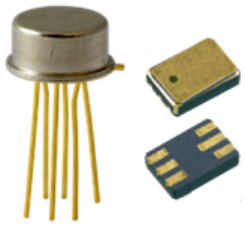
Hi-Reliability RAD Capable Optoisolator

HCC1000 / HCC1001

Features:

- TID Capable to 100Krad (SI)/cm2 ELDRS (0.1rad/s)
- Neutron capable to 1E12 neutrons (14MeV)
- TX & TXV Processing available to MIL-STD-19500
- 1 KV electrical Isolation
- Base Contact provided for conventional transistor biasing

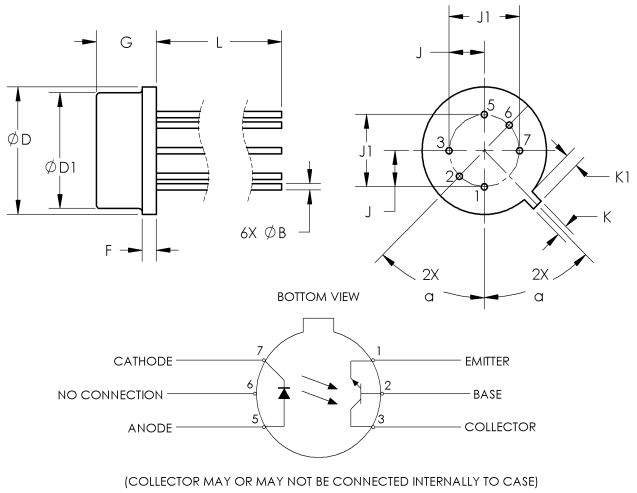


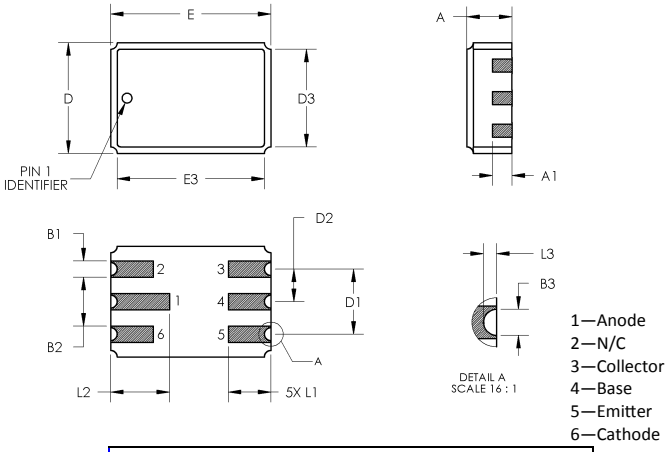
Description:

These devices are similar to Optek's 4N series of opto isolators with exception of the die. TX &TXV processing is per MIL-PRF-19500 and can be modified per customer SCDs. Each device consists of a IRLED & NPN transistor mounted in either hermetic TO-78 metal can, 6 pin SMD or custom packaging.

Applications:

Circuit electrical isolation in space applications such as satellites, launchers, space vehicles and planetary rovers





	DIMENSIONS			
	INCHES		MILLIMETERS	
LTR	MIN	MAX	MIN	MAX
ØD	0.335	0.370	8.51	9.40
ØD1	0.305	0.335	7.75	8.51
ØB	0.016	0.019	0.41	0.48
a	45° T.P.		45° T.P.	
F		0.040		1.02
G	0.155	0.185	3.94	4.70
J	.100 T.P.		2.54 T.P.	
J1	.200 T.P.		5.08 T.P.	
K	0.028	0.034	0.71	0.86
K1	0.029	0.045	0.74	1.14
L	0.500	0.600	12.70	15.24

	DIMENSIONS			
	INCHES		MILLIMETERS	
LTR	MIN	MAX	MIN	MAX
A	0.066	0.080	1.68	2.03
A1	0.026	0.034	0.66	0.86
B1	0.022	0.028	0.56	0.71
B2	.072 REF		1.83 REF	
B3	0.006	0.022	0.15	0.56
D	0.165	0.175	4.19	4.44
D1	0.095	0.105	2.41	2.67
D2	0.045	0.055	1.14	1.39
D3		0.175		4.44
E	0.240	0.250	6.10	6.35
E3		0.250		6.35
L1	0.060	0.070	1.65	1.78
L2	0.082	0.098	2.08	2.49
L3	0.003		0.08	

General Note
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Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range	-55° C to +150° C
Operating Temperature Range	-55° C to +150° C
Input-to-Output Isolation Voltage	± 1.00 kVDC(1)
Lead Soldering Temperature (TO-78 Metal Can) [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C(2)
Soldering Temperature (SMD) Vapor Phase Reflow for 30 seconds	215° C

Input Diode (LED)

Forward DC Current (65° C or below)	40 mA
Reverse Voltage	2 V
Power Dissipation	60 mW(3)

Output Phototransistor:

Continuous Collector Current	50 mA
Collector-Emitter Voltage	40 V
Collector-Base Voltage	45 V
Emitter-Base Voltage	7.0 V
Power Dissipation	300 mW(4)

Notes:
1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended.
3. Derate linearly 1.0 mW/° C above 65° C.
4. Derate linearly 3.0 mW/° C above 25° C.

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Performance

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage	0.80 1.00 0.70	- - -	1.70 1.9 1.50	V	I_F = 10.0 mA I_F = 10.0 mA, T_A = -55° C I_F = 10.0 mA, T_A = 125° C
I_R	Reverse Current	-	-	100	µA	V_R= 2.0 V
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	40	-	-	V	I_C = 1.0 mA, I_B= 0, I_F= 0
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	45	-	-	V	I_C = 100 µA, I_B= 0, I_F= 0
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	7	-	-	V	I_E = 100 µA, I_C= 0, I_F= 0
$I_{C(OFF)}$ [1]	Collector-Emitter Dark Current	-	-	100	nA	V_{CE} = 20 V, I_B= 0, I_F= 0
$I_{C(OFF)}$ [2]	Collector-Emitter Dark Current	-	-	100	µA	V_{CE} = 20 V, I_B= 0, I_F= 0, T_A = 100° C
$I_{CB(OFF)}$	Collector-Base Dark Current	-	-	10	nA	V_{CB} = 20 V, I_E= 0, I_F= 0
Coupled						
$I_{C(ON)}$	On-State Collector Current	1 15 10 15 2.8 2.0	- - - - - -	- - - - - -	mA	I_F = 1.0 mA, V_{CE} = 1.0 V, I_B = 0 I_F = 15.0 mA, V_{CE} = 1.0 V, I_B = 0 I_F = 10.0 mA, V_{CE} = 5.0 V, I_B = 0 I_F = 15.0 mA, V_{CE} = 5.0 V, I_B = 0 I_F = 2.0 mA, V_{CE} = 5.0 V, I_B = 0, T_A = -55° C I_F = 2.0 mA, V_{CE} = 5.0 V, I_B = 0, T_A = 100° C
$I_{CB(ON)}$	On-State Collector Base	30	-	-	µA	V_{CB} = 5 V, I_E = 0, I_F = 10 mA
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage	-	-	0.30	V	I_F = 20.0 mA, I_C = 10.0 mA, I_B = 0
H_{FE}	DC Current Gain	100	-	-	V	V_{CE} = 5.0 V , I_C = 10.0 mA, I_F = 0 mA
R_{IO}	Resistance (Input-to-Output)	10^{11}	-	-	Ω	V_{I-O} = ± 1000 VDC(1)
C_{IO}	Capacitance (Input-to-Output)	-	-	5	pF	V_{I-O} = 0 V, f = 1.0 MHz(1)
T_R, T_F	Rise and Fall Time	-	-	20	µs	V_{CC} = 10.0 V , I_F = 10.0 mA, R_L = 100 Ω

Notes:

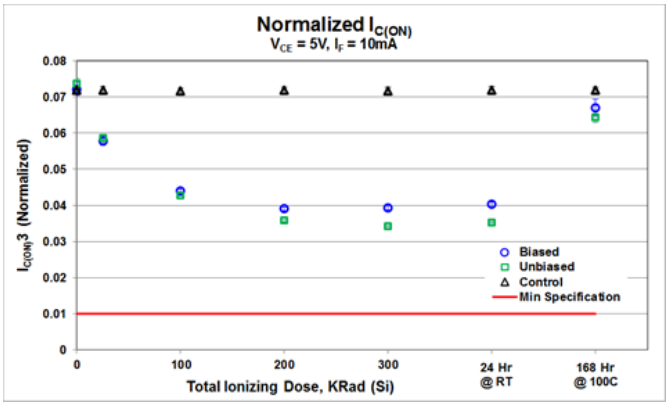
1. Measured with input leads shorted together and output leads shorted together.

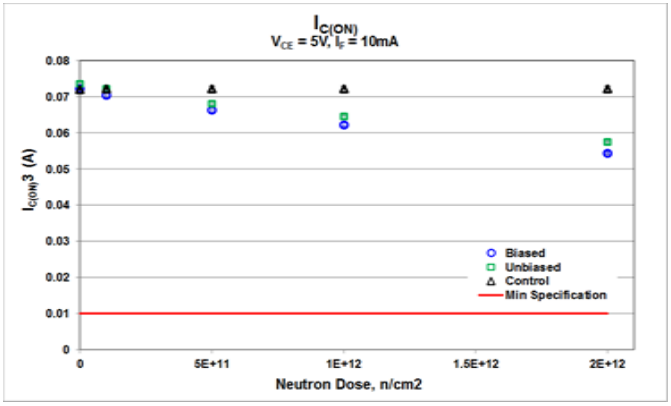
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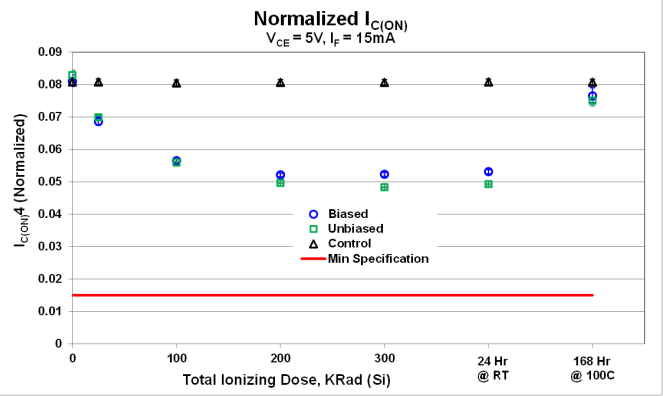
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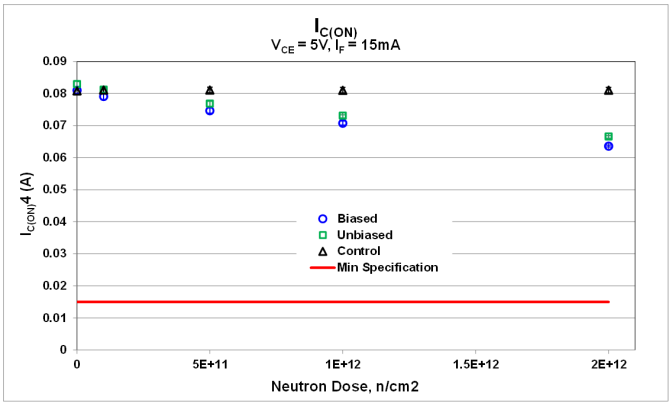
Radiation Test Standards:

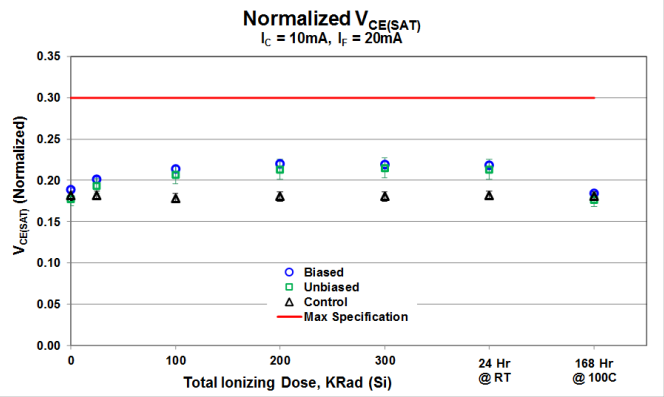
- **Total Ionizing Dose:** MIL-STD-883 Method 1019.7 and ASTM F1892-06
  (0.1rad (si)/s) dose rate
- **Neutron:** MIL-STD-883 Method1017.2 and ASTM Designation: E 772—94
- **Full Radiation report available**

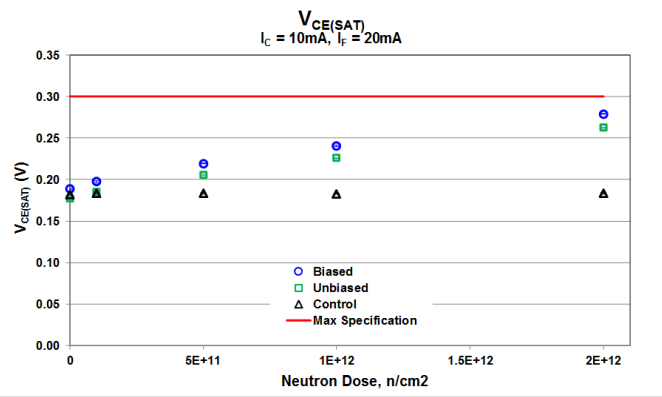












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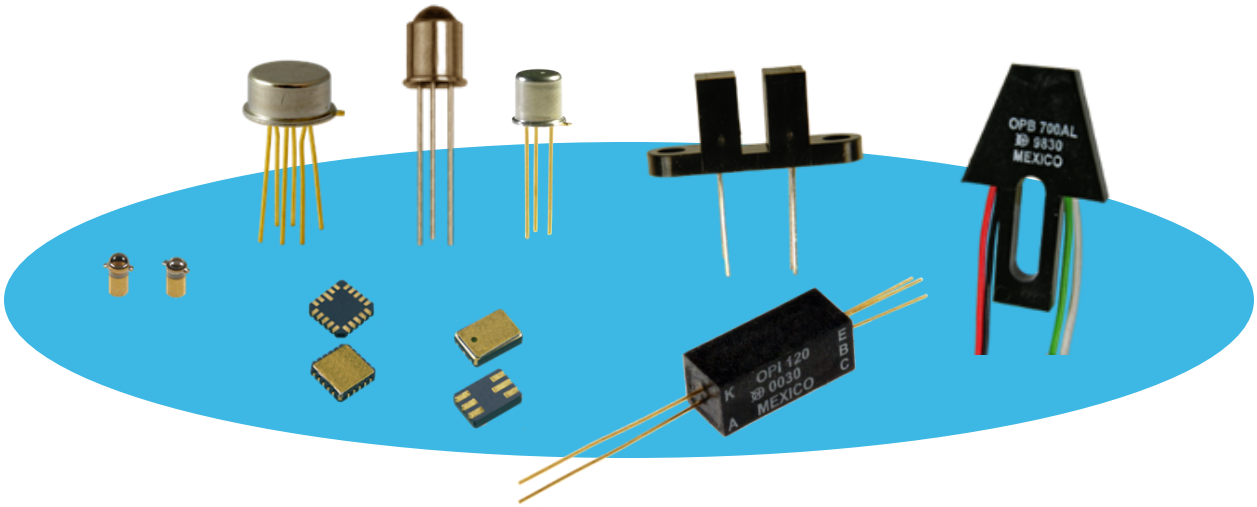
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Packaging

Package styles available:

Radiation testing was in a TO-78 can; functional & radiation samples can be supplied in discrete pairs such as, “pills” or TO-46 / TO-18 metal cans, 4 & 6 pin Hermetic Ceramic LLC, high voltage assemblies like the OPI120 and OPI150 hermetic high voltage isolators and more.



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Issue	Change Description	Approval	Date
A	Initial Preliminary Release	R. Bailey	3-23-16

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